Semiconductor	10 Amps Single-Phase Silicon Bridge Rectifiers						
Description	Mechanical Dimensions						
KBJ1000~1010	300 ± 0.3 300 ± 0.3 3.6 ± 0.2 3.6 ± 0.2 3.2 ± 0.2 3.5 ± 0.2 20.0 ± 0.3 11.0 ± 0.2 11.0 ± 0.2 11.0 ± 0.2 11.0 ± 0.2 0.7 ± 0.1 0.7 ± 0.2 2.7 ± 0.2						
KBJ-6 Feature	Dimensions in mm Mechanical Data						
This series is UL listed under the Recognized	Case: Molded plastic body over passivated junctions						
Component index, file number E142814	Polarity: Polarity symbols molded on body						
Plastic Package has Underwrites Laboratory	Terminals: Lead Solderable per MIL-STD-750						
Flammability Classification 84V-0	Method 2026						
High case dielectric strength of 1500Vrms	Mounting: any						
Ideal for Printed circuit boards	MountingTorque: 5 in-lbs max						
High surge current capability	Weight: 7.0grams(approx.)						

Max Ratings at Ta=25C Unless Otherwise Specified

Characteristic		KBJ							Unit
	Symbol	1000	1001	1002	1004	1006	1008	1010	
Peak Repetitive Reverse Voltage	Vrrm	50	100	200	400	600	800	1000	V
working Peak Reverse Voltage	Vrwm	35	70	140	280	420	560	700	V
DC Blocking Voltage	Vdc	50	100	200	400	600	800	1000	V
Forward Continuous Current	IF(AV)	10							Α
Peak Forward Surge Current 10ms Sine pulse, rated Vrrm applied	IFSM	170							А
Max Forward Voltage IF=10A @25C	Vf	1.05							V
Reverse Leakage Current WITH Vr @ 25C/125C	Ir	10/500							uA
Operating & Storage Temp. Range	Tj/Ts	-55 ~+150							С
Thermal Resistance Junction to Case	Rthja	2.6						C/W	
Thermal Resistance Case to Heatsink	Rthjc	5						C/W	
Rating for fusing(t<8.3ms)	I ² t	120						C/W	



10 Amps Single-Phase Silicon Bridge Rectifiers

Rating Characteristic Curves KBJ1000~1010(Ta=25C Unless otherwise noted)

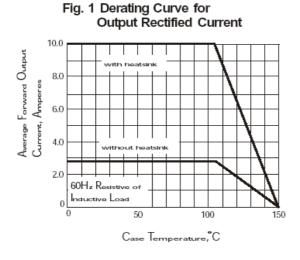


Fig. 3 Typical Instantaneous Forward Characteristics

